

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max T _A = +25°C	
-40V	25mΩ @ V _{GS} = -10V	-6.5A	
	45mΩ @ V _{GS} = -4.5V	-4.8A	

Description and Applications

This new generation MOSFET has been designed to minimize the onstate resistance ($R_{DS(ON)}$) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Motor controls
- Backlighting
- DC-DC converters
- Printer equipment

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low RDS(ON) Minimizes Conduction Losses
- Fast Switching Speed Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative.

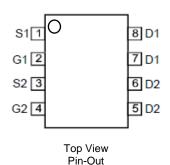
https://www.diodes.com/quality/product-definitions/

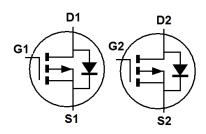
Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Lead
 Frame. Solderable per MIL-STD-202, Method 208(2)
- Weight: 0.074 grams (Approximate)

Top View

SO-8





Device Symbol

Ordering Information (Note 4)

Part Number	Bookago	Packing		
	Fackage	Qty.	Carrier	
DMP4026LSD-13	SO-8	2500	Reel	

Notes: 1

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\begin{array}{l} \bigcirc 1^{+} = \mbox{Manufacturer's Marking}\\ \hline \underline{P4}026LD = \mbox{Product Type Marking Code}\\ \hline \underline{YY}WW = \mbox{Date Code Marking}\\ \hline \hline \underline{YY} = \mbox{Year (ex: } 23 = 2023)\\ \hline WW = \mbox{Week (01 to 53)} \end{array}$



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	-40	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) $V_{GS} = -10V$	Steady State	T _A = +25°C T _A = +70°C	D	-6.5 -5.2	А
Maximum Body Diode Forward Current (Note 6)			ls	-6.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			IDM	-46	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			lsм	-46	A
Avalanche Current, L = 0.3mH			las	-20	А
Avalanche Energy, L = 0.3mH			E _{AS}	62	mJ

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Total Power Dissipation (Note 5)		PD	1.3	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	96.4	°C/W	
Total Power Dissipation (Note 6)		PD	1.7	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	73.1	°C/W	
Thermal Resistance, Junction to Case		Rejc	10.9	C/VV	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

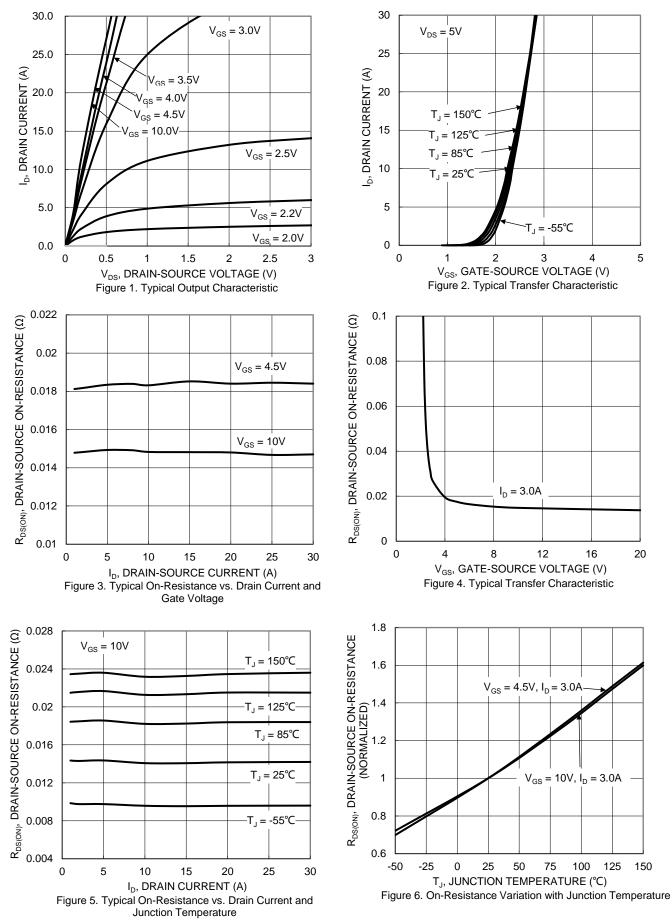
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	2				1		
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	$V_{GS} = 0V, I_D = -250\mu A$	
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-0.8	_	-1.8	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	D	_	15.1	25	mΩ	$V_{GS} = -10V, I_D = -3A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	18.3	45	mΩ	V _{GS} = -4.5V, I _D = -3A	
Diode Forward Voltage	Vsd	_	-0.7	-1.0	V	V _{GS} = 0V, I _S = -1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		2064			V _{DS} = -20V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss	_	212	_	pF		
Reverse Transfer Capacitance	Crss	_	183	_			
Gate Resistance	Rg	_	2.5	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Total Gate Charge (V _{GS} = -10V)	Q_{G}	_	45.8	_		V _{DS} = -20V, I _D = -3A	
Total Gate Charge (V _{GS} = -4.5V)	QG	_	23.5	_	nC		
Gate-Source Charge	QGS	_	5	_	nC		
Gate-Drain Charge	Q _{GD}	_	6.7	_			
Turn-On Delay Time	td(ON)	_	4.3	_		$V_{GS} = -10V, V_{DD} = -20V, R_G = 6\Omega,$ $I_D = -3A$	
Turn-On Rise Time	tR		4.7				
Turn-Off Delay Time	tD(OFF)		71.8	—	ns		
Turn-Off Fall Time	tF	_	23.9	_			
Body Diode Reverse Recovery Time	trr		17.3	—	ns	Is = -3A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	QRR		8.7	—	nC	Is = -3A, di/dt = 100A/µs	

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing. Notes:

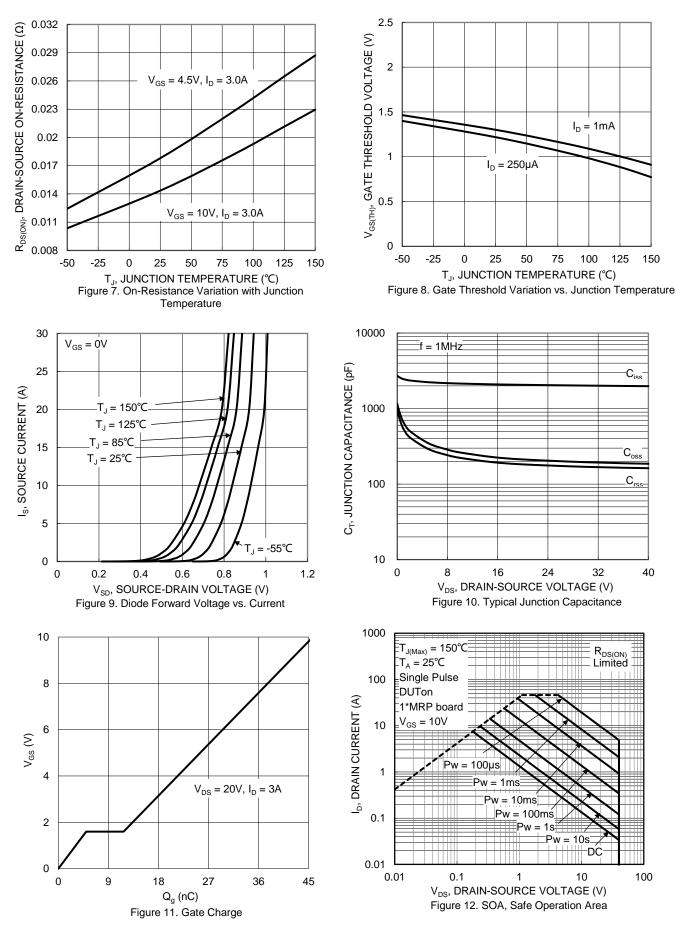


DMP4026LSD



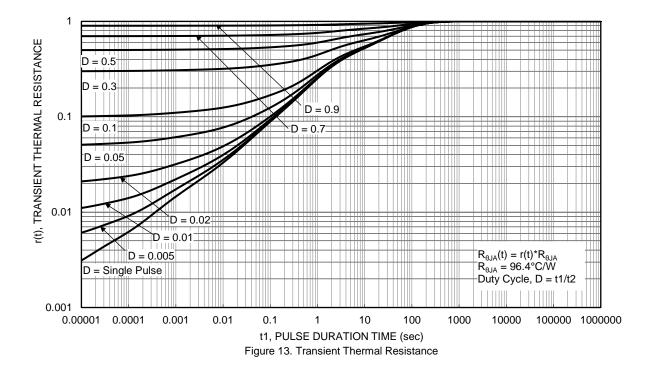
DMP4026LSD Document number: DS44830 Rev. 2 - 2





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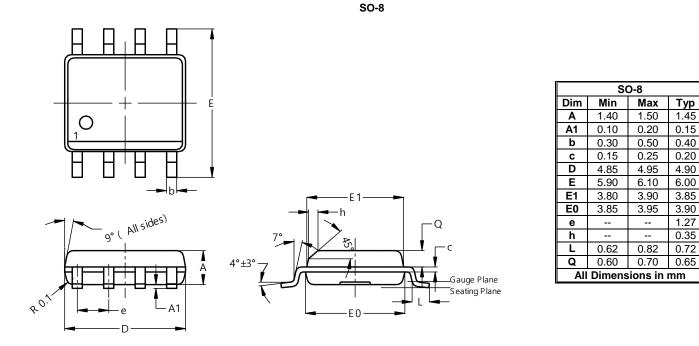


Тур

3.90

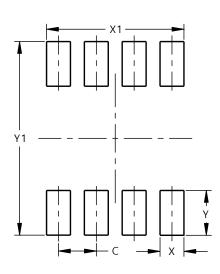
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

SO-8



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